

M.2 (P80) 4TE2

HIGHLIGHT FEATURES

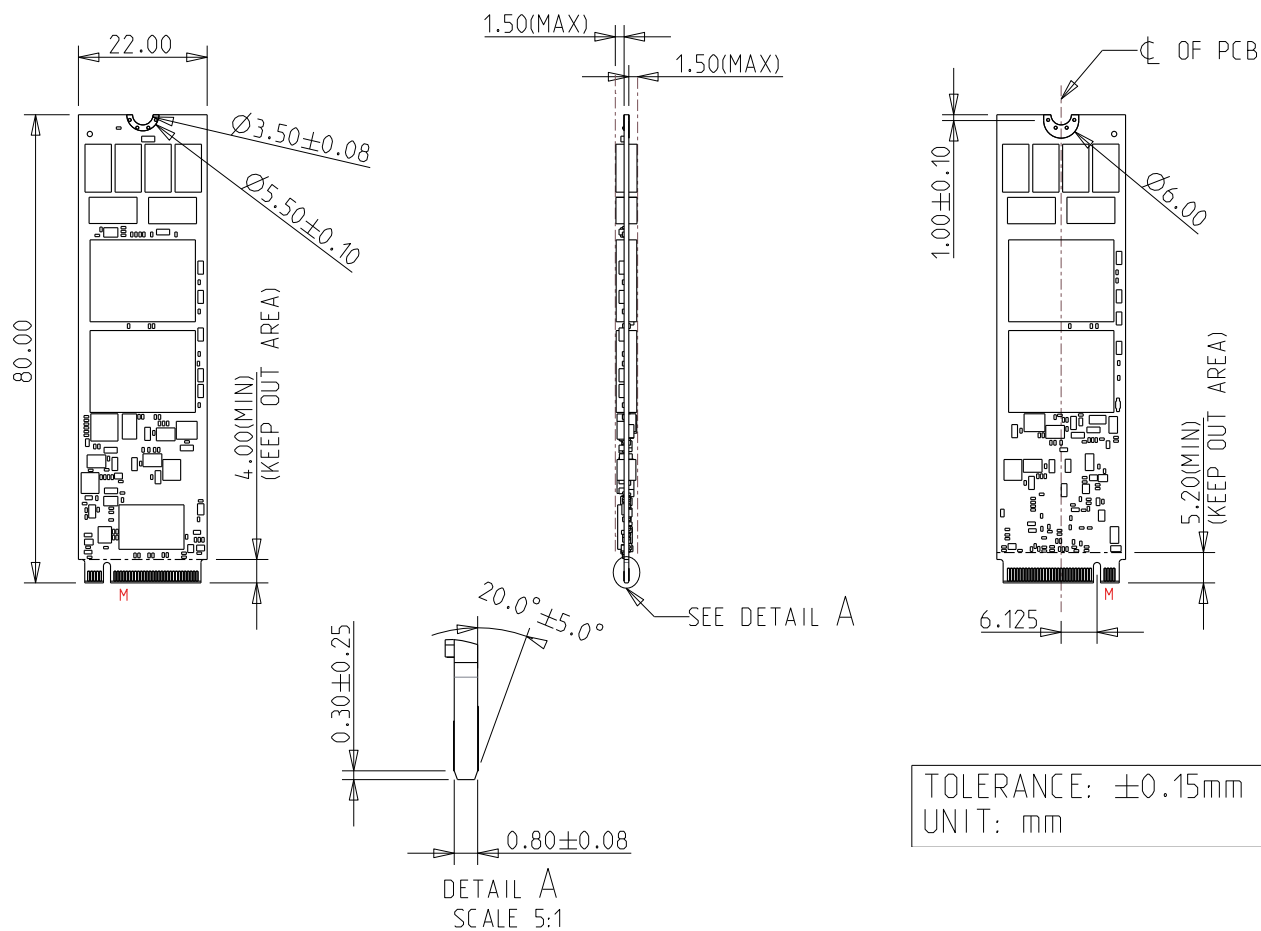


- Equipped with 112-layer 3D TLC NAND Flash
- Excellent data transfer speed
- Dynamic thermal management
- PLP (iCell) technology for power loss protection
- Support TCG Opal 2.0 (Optional)

SPECIFICATIONS

Model Name	M.2 (P80) 4TE2
Flash Type	3D TLC
Interface	PCIe Gen 4 x4
Form Factor	M.2 2280 M Key
Capacity	128GB ~ 2TB
Sequential R / W (MB/sec, max.)	3,550 / 3,000
P/E Cycle	3,000
TBW (Max.)	1,706
Storage Temperature	-40°C ~ 85°C
Max. Power Consumption	5.4W
Max. Channels	4
External DRAM Buffer	N
H/W Write Protect	Y (Optional)
S.M.A.R.T.	Y
AES	Y
TCG Opal	Y
Dimension (W x L x H/mm)	22.0 x 80.0 x 3.8
Vibration	20G@[7 ~ 2000Hz]
Shock	1500G@0.5ms
MTBF	>3 million hours
Warranty	3 Years

DIAGRAM



ORDER INFO.

Operating Temperature	Standard Grade (0°C ~ 70°C)
128GB	DEM28-A28DF1KCADL(P)
256GB	DEM28-B56DF1KCAQL(P)
512GB	DEM28-C12DF1KCAQL(P)
1TB	DEM28-01TDF1KCAQL(P)
2TB	DEM28-02TDF1KCAQL(P)

(P) : PLP (iCell) (Optional)

For TCG OPAL function, the PN Code 10th ~12th will be DF2.

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